

BFG92A/X NPN 5 GHz wideband transistor Rev. 06 — 12 March 2008

Product data sheet

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NXP Semiconductors



FEATURES

- High power gain
- Low noise figure
- Gold metallization ensures excellent reliability.

APPLICATIONS

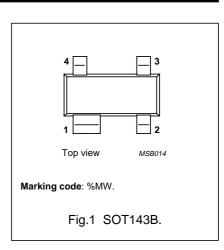
Wideband applications in the UHF and microwave range.

DESCRIPTION

Silicon NPN transistor in a 4-pin, dual-emitter SOT143B plastic package.

PINNING

| PIN | DESCRIPTION |
|-----|-------------|
| 1 | collector |
| 2 | emitter |
| 3 | base |
| 4 | emitter |



QUICK REFERENCE DATA

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|------------------|-------------------------------|--|------|------|------|------|
| V _{CBO} | collector-base voltage | | - | - | 20 | V |
| V _{CEO} | collector-emitter voltage | | - | - | 15 | V |
| I _C | collector current (DC) | | - | - | 25 | mA |
| P _{tot} | total power dissipation | $T_s \le 60 \ ^{\circ}C$ | - | - | 400 | mW |
| C _{re} | feedback capacitance | I _C = i _c = 0; V _{CB} = 10 V; f = 1 MHz | - | 0.35 | _ | pF |
| f _T | transition frequency | I _C = 15 mA; V _{CE} = 10 V; f = 500 MHz | 3.5 | 5 | - | GHz |
| G _{UM} | maximum unilateral power gain | I_{C} = 15 mA; V_{CE} = 10 V; T_{amb} = 25 °C; f = 1 GHz | - | 16 | _ | dB |
| | | I_{C} = 15 mA; V_{CE} = 10 V; T_{amb} = 25 °C; f = 2 GHz | - | 11 | - | dB |
| F | noise figure | | - | 2 | _ | dB |

Product specification

BFG92A/X

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|------------------|---------------------------|--|------|------|------|
| V _{CBO} | collector-base voltage | open emitter | _ | 20 | V |
| V _{CEO} | collector-emitter voltage | open base | - | 15 | V |
| V _{EBO} | emitter-base voltage | open collector | - | 2 | V |
| I _C | collector current (DC) | | - | 25 | mA |
| P _{tot} | total power dissipation | $T_s \le 60 \text{ °C}; \text{ note } 1$ | - | 400 | mW |
| T _{stg} | storage temperature range | | -65 | 150 | °C |
| Tj | junction temperature | | _ | 175 | °C |

Note

1. T_s is the temperature at the soldering point of the collector pin.

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | CONDITIONS | VALUE | UNIT |
|---------------------|---|------------|-------|------|
| R _{th j-s} | thermal resistance from junction to soldering point | note 1 | 290 | K/W |

Note

1. T_s is the temperature at the soldering point of the collector pin.

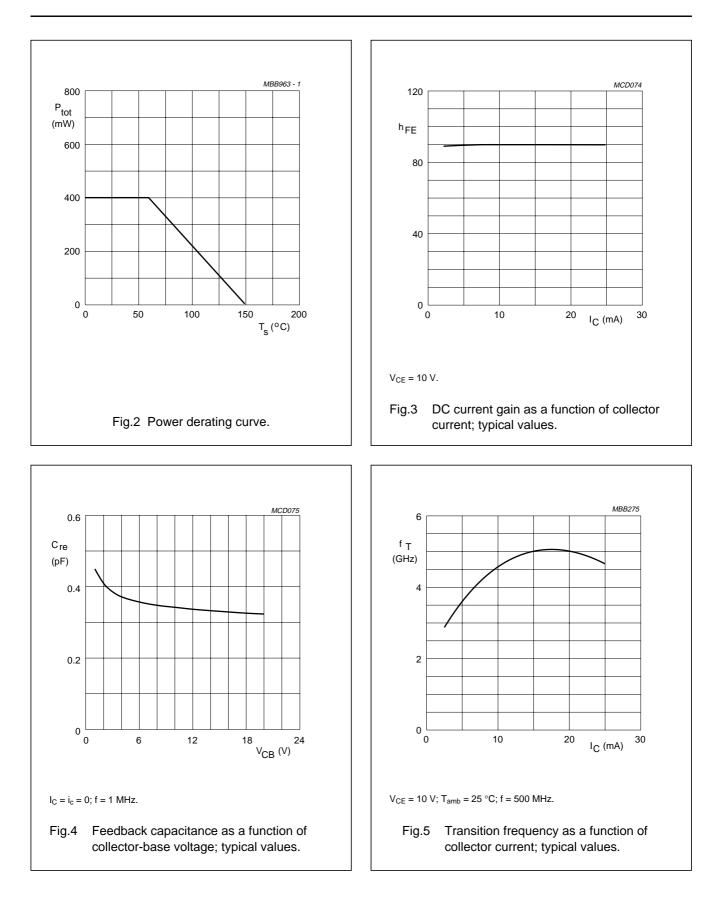
CHARACTERISTICS

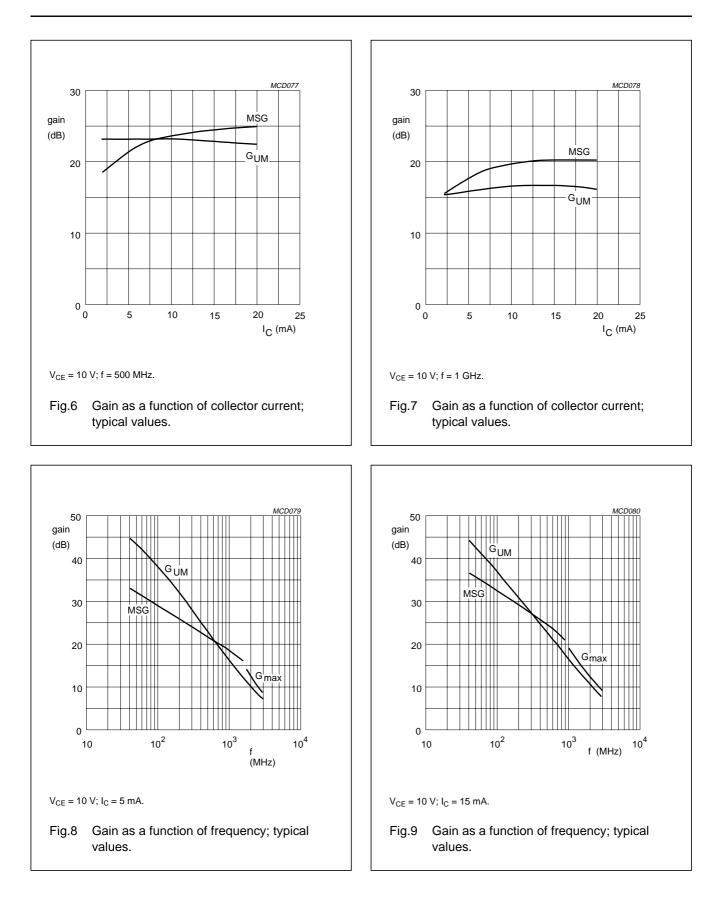
 $T_i = 25 \ ^{\circ}C$ unless otherwise specified.

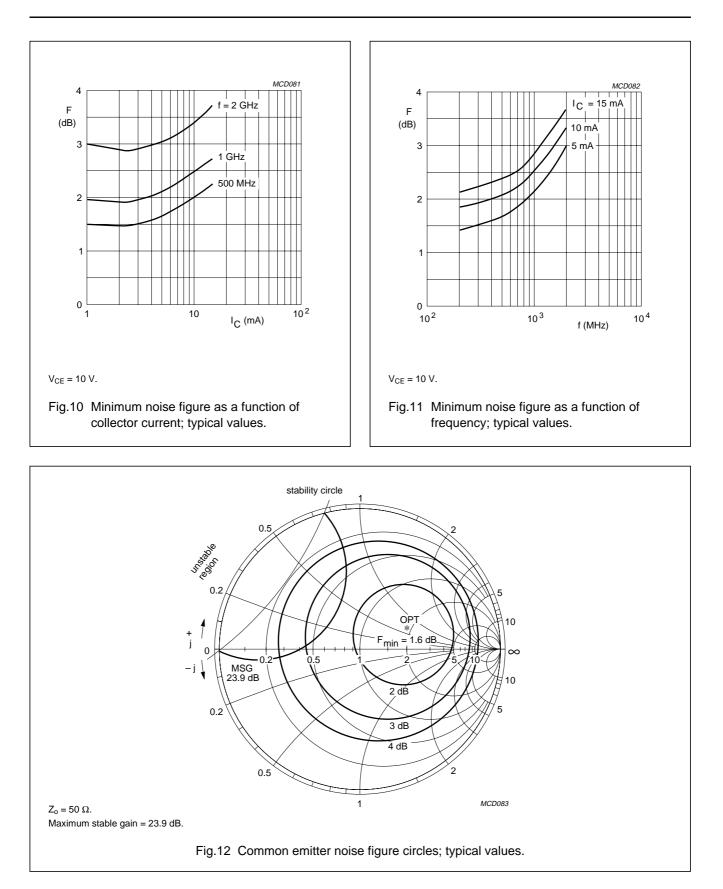
| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|------------------|---------------------------------------|---|------|------|------|------|
| I _{CBO} | collector leakage current | I _E = 0; V _{CB} = 10 V | - | - | 50 | nA |
| h _{FE} | DC current gain | I _C = 15 mA; V _{CE} = 10 V | 65 | 90 | 135 | |
| C _c | collector capacitance | I _E = i _e = 0; V _{CB} = 10 V; f = 1 MHz | - | 0.6 | - | pF |
| Ce | emitter capacitance | $I_{C} = i_{c} = 0; V_{EB} = 10 V; f = 1 MHz$ | - | 0.9 | - | pF |
| C _{re} | feedback capacitance | I _C = i _c = 0; V _{CB} = 10 V; f = 1 MHz | - | 0.35 | - | pF |
| f _T | transition frequency | I _C = 15 mA; V _{CE} = 10 V; f = 500 MHz | 3.5 | 5 | - | GHz |
| G _{UM} | maximum unilateral power gain; note 1 | I_C = 15 mA; V_{CE} = 10 V; T_{amb} = 25 °C; f = 1 GHz | - | 16 | - | dB |
| | | $I_{C} = 15 \text{ mA}; V_{CE} = 10 \text{ V};$ $T_{amb} = 25 \text{ °C}; \text{ f} = 2 \text{ GHz}$ | - | 11 | - | dB |
| F | noise figure | $\begin{split} \Gamma_{s} &= \Gamma_{opt}; \ I_{C} = 5 \text{ mA}; \ V_{CE} = 10 \text{ V}; \\ T_{amb} &= 25 \ ^{\circ}\text{C}; \ f = 1 \text{ GHz} \end{split}$ | - | 2 | - | dB |
| | | | - | 3 | - | dB |

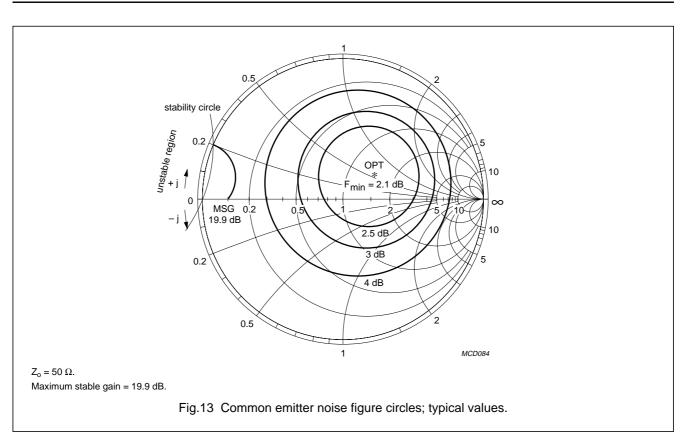
Note

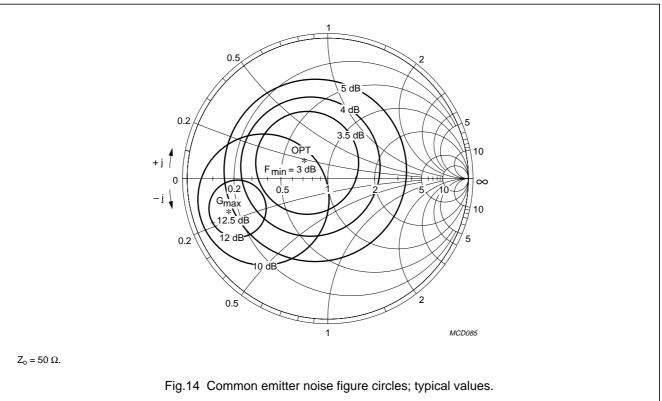
1. G_{UM} is the maximum unilateral power gain, assuming S_{12} is zero and $G_{UM} = 10 \log \frac{|S_{21}|^2}{(1-|S_{11}|^2)(1-|S_{22}|^2)} dB$.

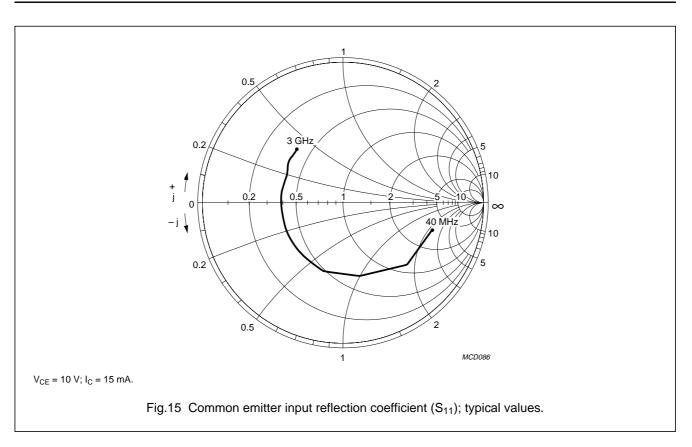


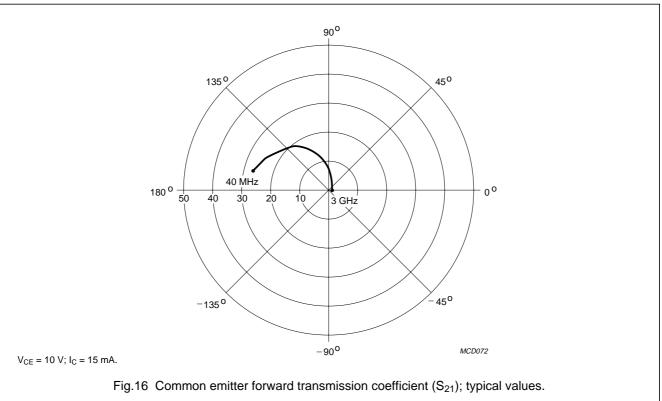


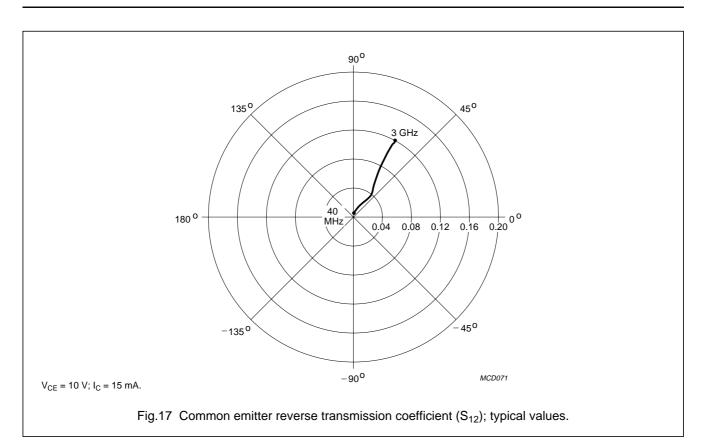


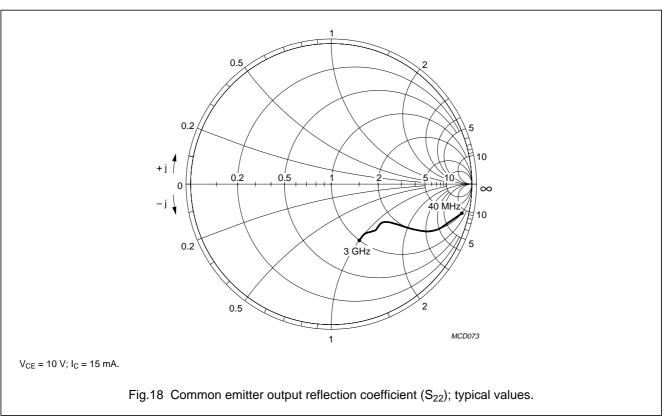












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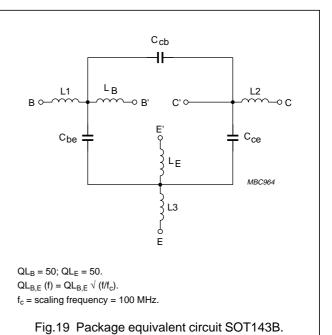
SPICE parameters for BFR90A/X die

| SEQUENCE No. | PARAMETER | VALUE | UNIT |
|--------------|-----------|-------|------|
| 1 | IS | 411.8 | aA |
| 2 | BF | 102.6 | _ |
| 3 | NF | 997.2 | m |
| 4 | VAF | 62.67 | V |
| 5 | IKF | 3.200 | A |
| 6 | ISE | 4.010 | fA |
| 7 | NE | 1.577 | _ |
| 8 | BR | 18.10 | - |
| 9 | NR | 996.2 | m |
| 10 | VAR | 3.369 | V |
| 11 | IKR | 1.281 | A |
| 12 | ISC | 279.9 | aA |
| 13 | NC | 1.075 | _ |
| 14 | RB | 10.00 | Ω |
| 15 | IRB | 1.000 | μA |
| 16 | RBM | 10.00 | Ω |
| 17 | RE | 1.164 | Ω |
| 18 | RC | 2.320 | Ω |
| 19 (note 1) | ХТВ | 0.000 | _ |
| 20 (note 1) | EG | 1.110 | eV |
| 21 (note 1) | ХТІ | 3.000 | _ |
| 22 | CJE | 890.5 | fF |
| 23 | VJE | 600.0 | mV |
| 24 | MJE | 258.5 | m |
| 25 | TF | 15.49 | ps |
| 26 | XTF | 39.14 | _ |
| 27 | VTF | 2.152 | V |
| 28 | ITF | 213.7 | mA |
| 29 | PTF | 0.000 | deg |
| 30 | CJC | 546.5 | fF |
| 31 | VJC | 380.8 | mV |
| 32 | MJC | 202.9 | m |
| 33 | XCJC | 150.0 | m |
| 34 | TR | 5.618 | ns |
| 35 (note 1) | CJS | 0.000 | F |

| SEQUENCE No. | PARAMETER | VALUE | UNIT |
|--------------|-----------|-------|------|
| 36 (note 1) | VJS | 750.0 | mV |
| 37 (note 1) | MJS | 0.000 | - |
| 38 | FC | 850.0 | m |

Note

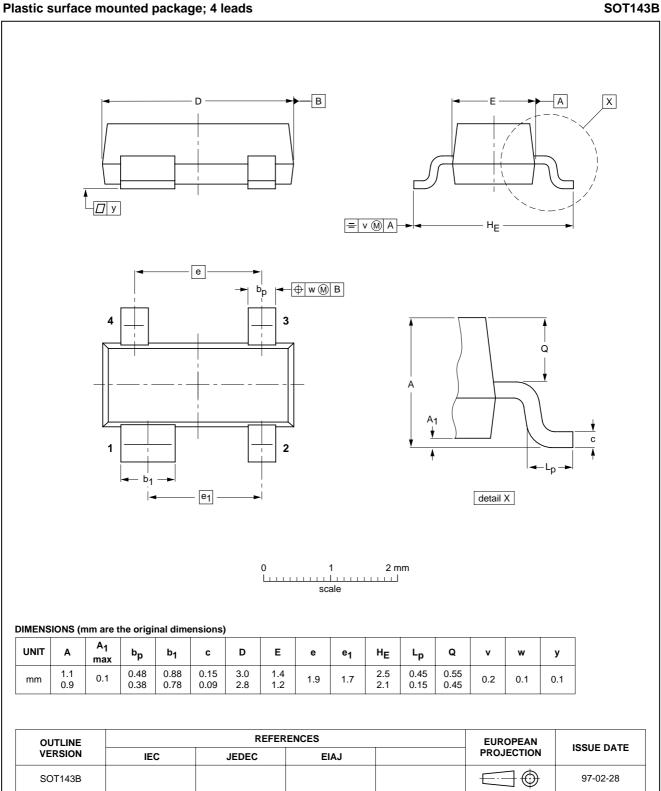
1. These parameters have not been extracted, the default values are shown.



List of components (see Fig.19)

| DESIGNATION | VALUE | UNIT |
|-----------------|-------|------|
| C _{be} | 84 | fF |
| C _{cb} | 17 | fF |
| C _{ce} | 191 | fF |
| L1 | 0.12 | nH |
| L2 | 0.21 | nH |
| L3 | 0.06 | nH |
| L _B | 0.95 | nH |
| LE | 0.40 | nH |

PACKAGE OUTLINES



0074405

Legal information

Data sheet status

| Document status[1][2] | Product status ^[3] | Definition |
|--------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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Revision history

| Revision history | | | | |
|-------------------------------|-----------------------------------|---------------------------------|---------------|----------------|
| Document ID | Release date | Data sheet status | Change notice | Supersedes |
| BFG92AX_N_6 | 20080312 | Product data sheet | - | BFG92AX_N_5 |
| Modifications: | Characteristi | ics Table; DC current gain valu | e changed | |
| BFG92AX_N_5 | 20071126 | Product data sheet | - | BFG92AX_4 |
| BFG92AX_4 (9397 750 04344) | 19980923 | Product specification | - | BFG92SERIES_3 |
| BFG92SERIES_3 | 19950912 | Product specification | - | BFG92SERIES_2 |
| BFG92SERIES_2 | 19921101 | Product specification | - | BFG92_SERIES_1 |
| BFG92_SERIES_1 | - | - | - | - |

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